M9601A PXIe Precision Source / Measure Unit, 1.25 MSa/s, 10 fA, 210 V, 315 mA

The high-performance PXIe source / measure unit (SMU) enables faster precise dynamic measurement from DC to 20 µs pulse, output up to 210 V/315 mA, and 10 fA resolution.



Key Features

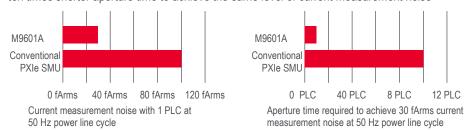
- symmetry 4-guadrant and wide range operation up to 210 V and 315 mA
- best-in-class 10 fA /500 nV resolution
- narrow pulse width to 20 μs
- fast transient response 150 μ s (from 0 V to 200 V); settling time with 1.4 V/ μ s maximum slew rate
- fast sampling rate up to 1.25 MSa/s with1 Mpts memory depth

Typical Applications

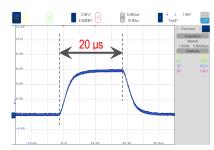
- optical devices (laser diodes, photo diodes, LED)
- semiconductor devices (FET, diodes, transistors)
- resistors, diodes, varistors, and other component devices

Low current measurement noise performance reduces the measurement time

- ✓ three times lower current measurement noise 1 power line cycle (PLC) aperture time
- ten times shorter aperture time to achieve the same level of current measurement noise



Narrow pulse suppresses self-heating effect



Fast transient response captures the actual transient response from the devices and

circuits



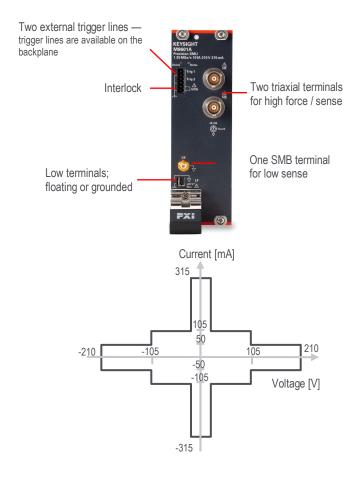
Learn more at: www.keysight.com



Key Specifications and Characteristics:

Parameters			Values
Output	Maximum voltage		210 V
	Maximum current (DC / pulse)		315 mA / 315 mA
	Quadrant operation	Quadrant operation	
Current	Minimum resolution		10 fA
	RMS noise ¹	1 PLC	30 fArms
		10 PLC	10 fArms
	Source noise 0.1 Hz to 10 Hz ¹		200 fApp
Voltage	Minimum resolution		500 nV
	Source noise ¹	0.1 – 10 Hz	4 μVpp
		20 MHz bandwidth	< 25 mVpp
		200 MHz bandwidth	< 50 mVpp
Dynamic measurement	Minimum pulse width		20 μs
	Maximum slew rate ¹		> 1.4 V/µs
	Sampling rate		1.25 MSa/s
Slots / module			2-slot
Channel / module			1-channel

^{1.} Supplemental characteristics, Refer to M9601A datasheet for details.



Learn more at: www.keysight.com